SWITCHMODE[™] Power Rectifiers

... designed for use in switching power supplies, inverters and as free wheeling diodes, these state-of-the-art devices have the following features:

- Ultrafast 35 and 60 Nanosecond Recovery Time
- 175°C Operating Junction Temperature
- High Voltage Capability to 600 Volts
- Low Forward Drop
- Low Leakage Specified @ 150°C Case Temperature
- Current Derating Specified @ Both Case and Ambient Temperatures
- Epoxy Meets UL94, V_O @ 1/8"
- High Temperature Glass Passivated Junction

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 4.3 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 30 units per plastic tube
- Marking: U3020, U3040, U3060

MAXIMUM RATINGS

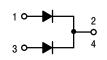
Please See the Table on the Following Page

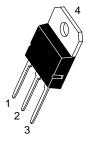


ON Semiconductor[™]

http://onsemi.com

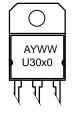
ULTRAFAST RECTIFIERS 30 AMPERES 200–600 VOLTS





TO-218AC CASE 340D STYLE 2

MARKING DIAGRAM



A = Assembly Location Y = Year WW = Work Week U30x0 = Device Code

= 2, 4 or 6

- 2, 1010

х

ORDERING INFORMATION

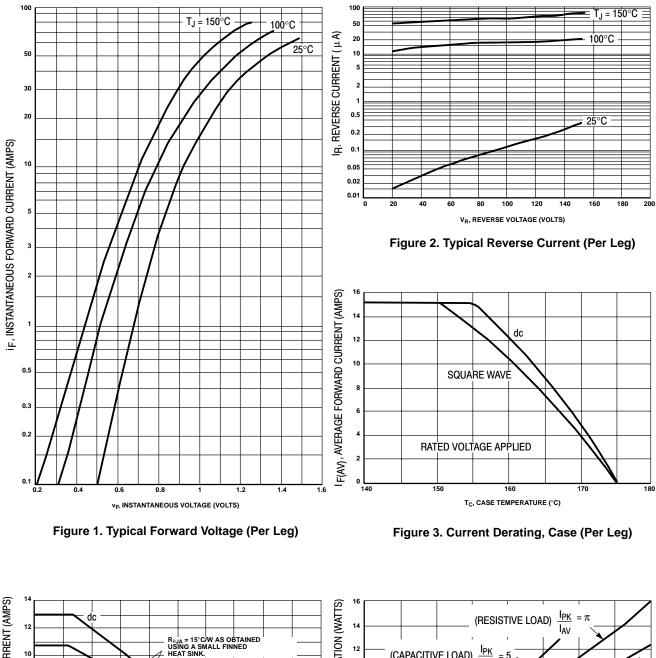
Device	Package	Shipping
MUR3020PT	SOT-93	30 Units/Rail
MUR3040PT	SOT-93	30 Units/Rail
MUR3060PT	SOT-93	30 Units/Rail

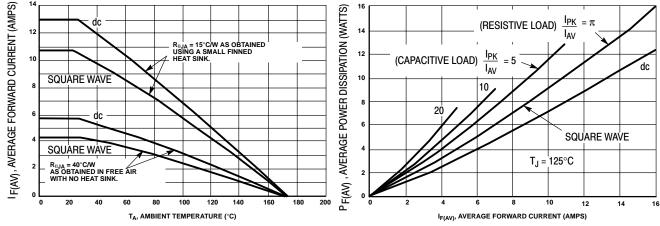
Rating	Symbol	MUR3020PT	MUR3040PT	MUR3060PT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	200	400	600	Volts
Average Rectified Forward Current (Rated V _R) Per Leg Per Device	I _{F(AV)}	$\begin{array}{cccc} 15 @ T_{C} = 150^{\circ}C & 15 @ T_{C} = \\ 30 @ T_{C} = 150^{\circ}C & 30 & 145^{\circ}C \end{array}$		Amps	
Peak Rectified Forward Current, Per Leg (Rated V _R , Square Wave, 20 kHz, T _C = 150°C)	I _{FRM}	-	30 30 @ T _C = 150°C @ T _C =145°C		Amps
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions, halfwave, single phase, 60 Hz) Per Leg	I _{FSM}	200	150		Amps
Operating Junction and Storage Temperature	T _J , T _{stg}	– 65 to +175		°C	
THERMAL CHARACTERISTICS (Per Diode Leg)					
Maximum Thermal Resistance — Junction to Case — Junction to Ambient	R _{θJC} R _{θJA}	1.5 40		°C/W	
ELECTRICAL CHARACTERISTICS (Per Diode Leg)					
Maximum Instantaneous Forward Voltage (Note 1.) ($I_F = 15 \text{ Amp}, T_C = 150^{\circ}\text{C}$) ($I_F = 15 \text{ Amp}, T_C = 25^{\circ}\text{C}$)	V _F	0.85 1.05	1.12 1.25	1.2 1.5	Volts
Maximum Instantaneous Reverse Current (Note 1.) (Rated DC Voltage, $T_J = 150^{\circ}C$) (Rated DC Voltage, $T_J = 25^{\circ}C$)	İR	500 1000 10 10		μA	
Maximum Reverse Recovery Time (i _F = 1.0 Amp, di/dt = 50 Amps/μs)	t _{rr}	35 60		ns	

MAXIMUM RATINGS (Per Leg)

1. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.







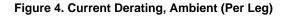
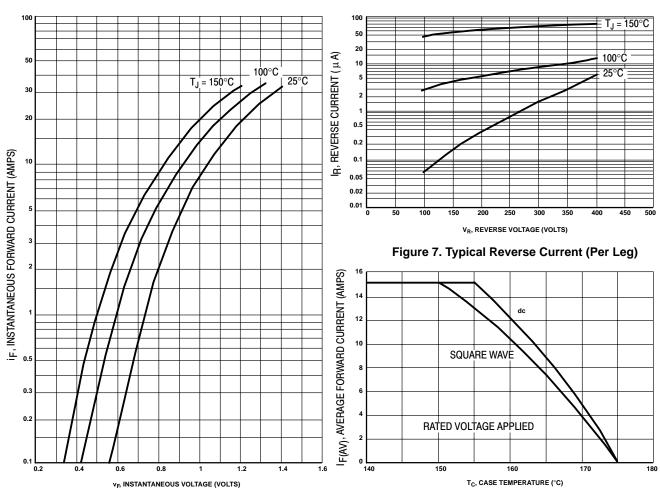


Figure 5. Power Dissipation (Per Leg)





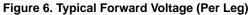


Figure 8. Current Derating, Case (Per Leg)

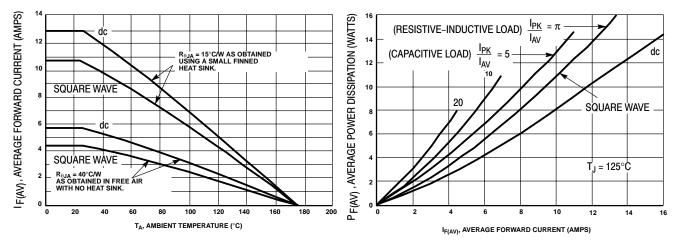
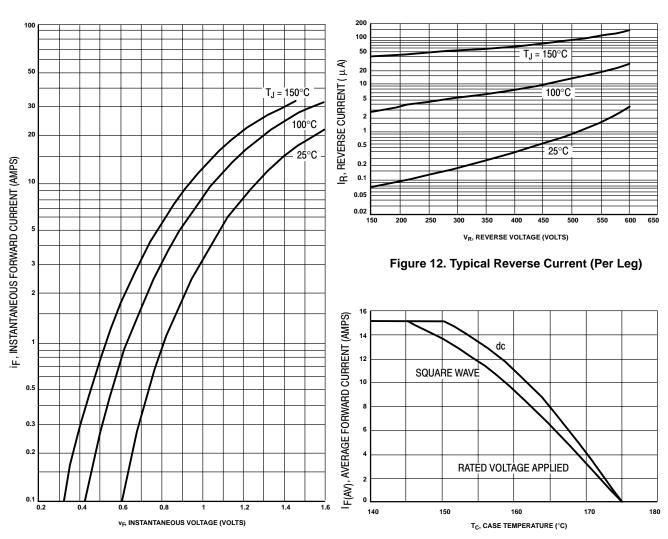


Figure 9. Current Derating, Ambient (Per Leg)





MUR3060PT

Figure 11. Typical Forward Voltage (Per Leg)

Figure 13. Current Derating, Case (Per Leg)

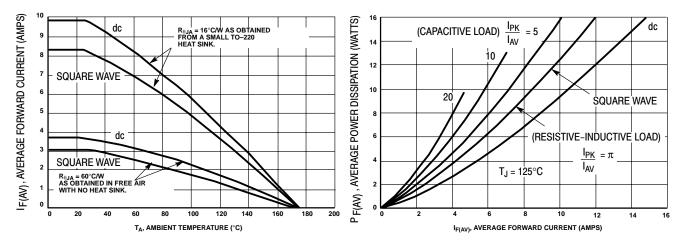
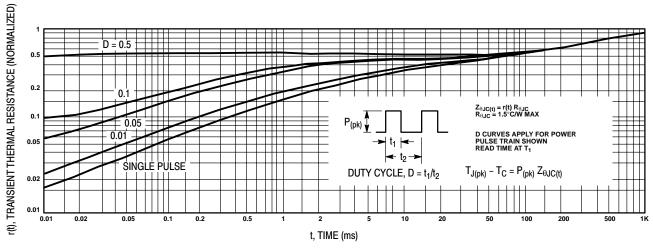
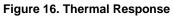


Figure 14. Current Derating, Ambient (Per Leg)







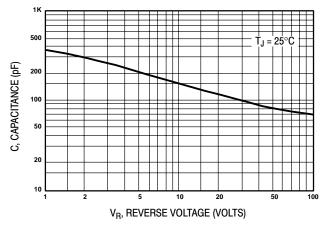
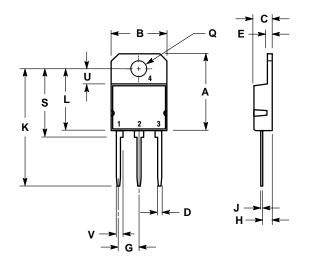


Figure 17. Typical Capacitance (Per Leg)

PACKAGE DIMENSIONS

TO-218 THREE LEAD TO-218 CASE 340D-02 **ISSUE E**



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α		20.35		0.801	
В	14.70	15.20	0.579	0.598	
С	4.70	4.90	0.185	0.193	
D	1.10	1.30	0.043	0.051	
E	1.17	1.37	0.046	0.054	
G	5.40	5.55	0.213	0.219	
Н	2.00	3.00	0.079	0.118	
ſ	0.50	0.78	0.020	0.031	
K	31.00 REF		1.220 REF		
L		16.20		0.638	
Q	4.00	4.10	0.158	0.161	
S	17.80	18.20	0.701	0.717	
U	4.00 REF		0.157 REF		
۷	1.75 REF		0.069		

STYLE 2: PIN 1. ANODE 1 2. CATHODE(S) 3. ANODE 2 4. CATHODE(S)

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